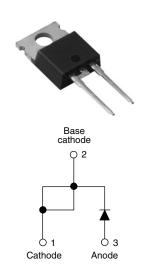


Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 6 A



TO-220AC

| PRODUCT SUMMARY | | | | |
|--|----------|--|--|--|
| V _R | 1200 V | | | |
| V _F at 6 A at 25 °C | 3.0 V | | | |
| I _{F(AV)} | 6 A | | | |
| t _{rr} (typical) | 26 ns | | | |
| T _J (maximum) | 150 °C | | | |
| Q _{rr} (typical) | 116 nC | | | |
| dI _{(rec)M} /dt (typical) at 125 °C | 100 A/μs | | | |
| I _{RRM} (typical) | 4.4 A | | | |

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- · Specified at operating conditions
- · Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA06TB120 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 6 A continuous current, the HFA06TB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the th portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA06TB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|-----------------------------------|-------------------------|---------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Cathode to anode voltage | V_{R} | | 1200 | V | |
| Maximum continuous forward current | I _F | T _C = 100 °C | 6 | | |
| Single pulse forward current | I _{FSM} | | 80 | Α | |
| Maximum repetitive forward current | I _{FRM} | | 24 | | |
| Maximum navar dissination | Б | T _C = 25 °C | 62.5 | W | |
| Maximum power dissipation | P _D | T _C = 100 °C | 25 | VV | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | - 55 to + 150 | °C | |

HFA06TB120

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| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|--|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V _{BR} | Ι _R = 100 μΑ | 1200 | - | - | |
| | | I _F = 6.0 A | - | 2.7 | 3.0 | V |
| Maximum forward voltage V _{FM} | V_{FM} | I _F = 12 A | - | 3.5 | 3.9 | |
| | I _F = 6.0 A, T _J = 125 °C | - | 2.4 | 2.8 | | |
| Maximum reverse | | $V_R = V_R$ rated | - | 0.26 | 5.0 | |
| leakage current | T _J = 125 °C, V _R = 0.8 x V _R rated | - | 110 | 500 | μA | |
| Junction capacitance | C _T | V _R = 200 V | - | 9.0 | 14 | pF |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH |

| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|---------------------------|--|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | t _{rr} | $I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | - | 26 | - | |
| Reverse recovery time | t _{rr1} | T _J = 25 °C | | - | 53 | 80 | ns |
| | t _{rr2} | T _J = 125 °C | $I_F = 6.0 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$ | - | 87 | 130 | |
| Peak recovery current | I _{RRM1} | T _J = 25 °C | | - | 4.4 | 8.0 | A |
| | I _{RRM2} | T _J = 125 °C | | - | 5.0 | 9.0 | |
| Reverse recovery charge | Q _{rr1} | T _J = 25 °C | | - | 116 | 320 | nC |
| | Q _{rr2} | T _J = 125 °C | | - | 233 | 585 | |
| Peak rate of recovery current during t _b | dI _{(rec)M} /dt1 | T _J = 25 °C | | - | 180 | - | A/µs |
| | dI _{(rec)M} /dt2 | T _J = 125 °C | | - | 100 | - | γ./μδ |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-------------------|--|--------------|-------|------------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Lead temperature | T _{lead} | 0.063" from case (1.6 mm) for 10 s | - | - | 300 | °C |
| Thermal resistance, junction to case | R _{thJC} | | - | - | 2.0 | |
| Thermal resistance, junction to ambient | R _{thJA} | Typical socket mount | - | - | 80 | K/W |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | |
| Woight | | | - | 2.0 | - | g |
| Weight | | - | 0.07 | - | oz. | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) |
| Marking device | | Case style TO-220AC | | HFA06 | TB120 | |



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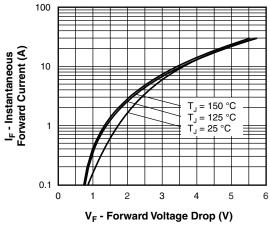


Fig. 1 - Typical Forward Voltage Drop Characteristics

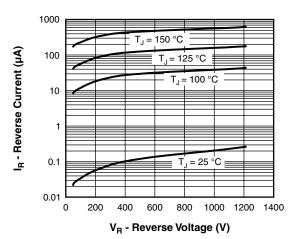


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

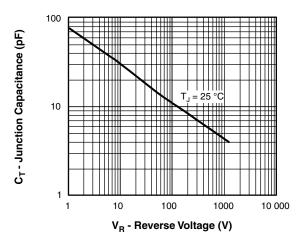


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

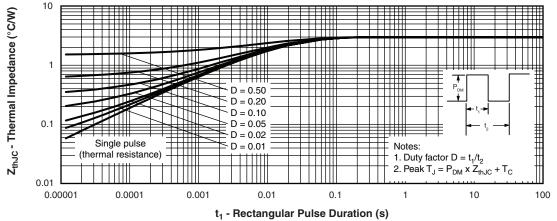


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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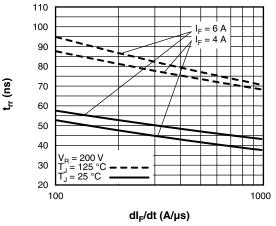


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

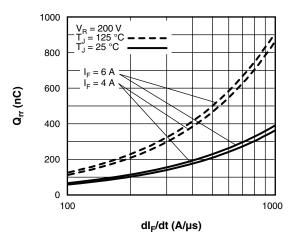


Fig. 7 - Typical Stored Charge vs. dl_F/dt

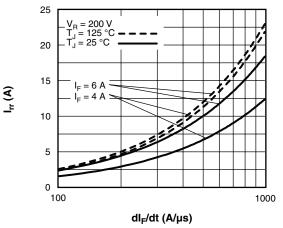


Fig. 6 - Typical Recovery Current vs. dl_F/dt

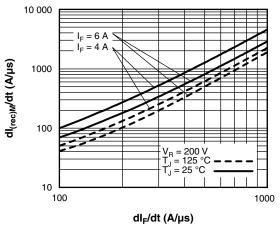


Fig. 8 - Typical $dl_{(rec)M}/dt$ vs. dl_F/dt



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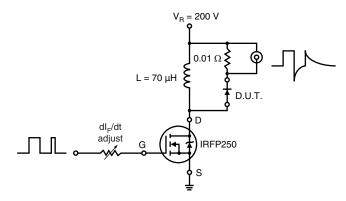
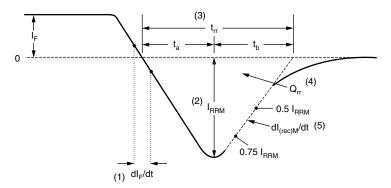


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code | HF | A | 06 | TB | 120 | -

1 - HEXFRED® family

Process designator:

A = subs. elec. irrad.

B = subs. platinum

3 - Current rating (06 = 6 A)

- Package outline (TB = TO-220 2 lead)

5 - Voltage rating (120 = 1200 V)

6 - • None = Standard production

• PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS | | | | | |
|--|---------------------------------|--|--|--|--|
| Dimensions http://www.vishay.com/doc?95221 | | | | | |
| Part marking information | http://www.vishay.com/doc?95224 | | | | |



Vishay

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